

# **Topic 13**

## 13 Light emitting diodes (LEDs) -2

13.1 Burrus surface emitter

13.2 Edge emitter

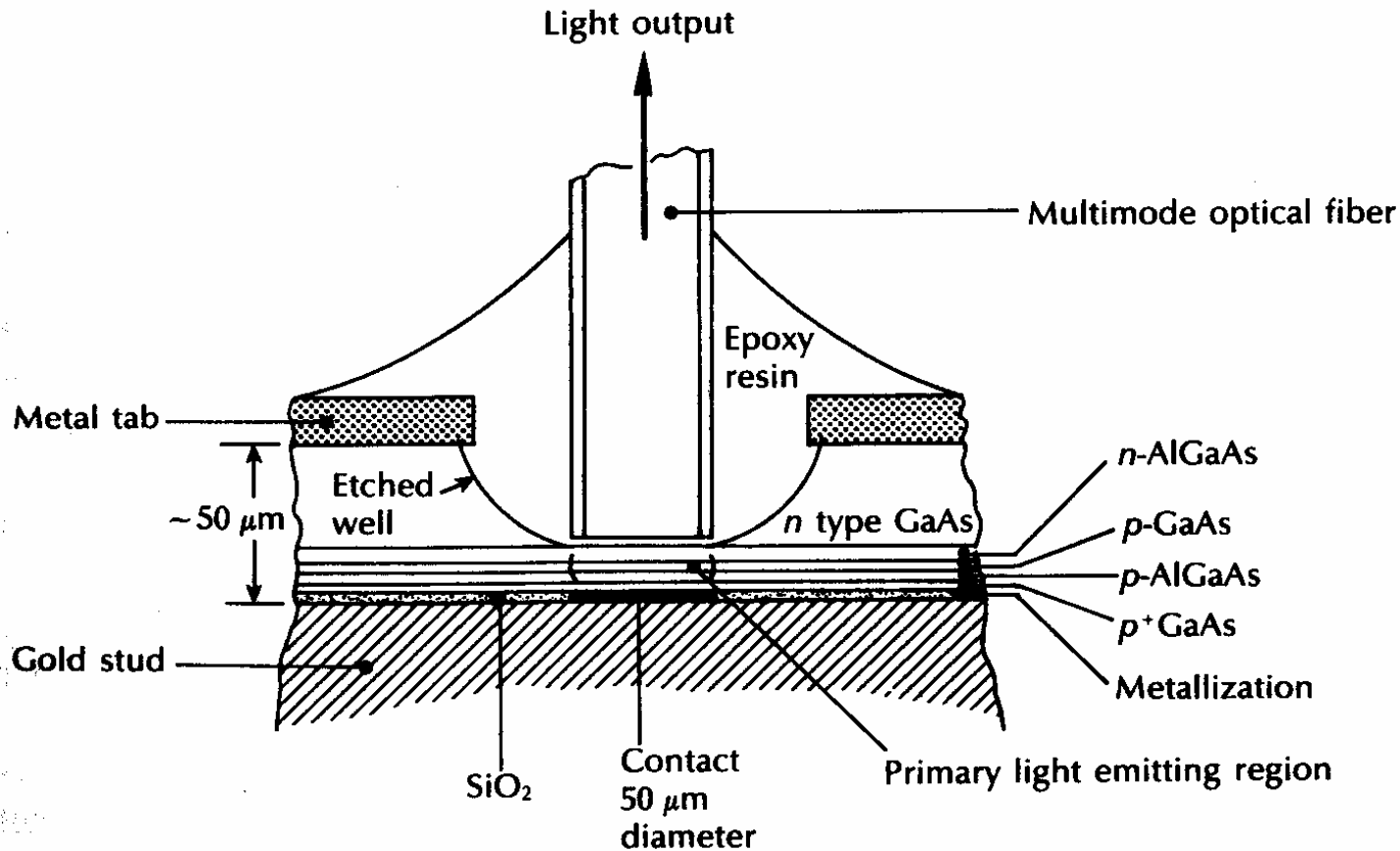
13.3 Coupling to fibre

13.4 Fabrication of LEDs

13.5 Special applications using UV LED

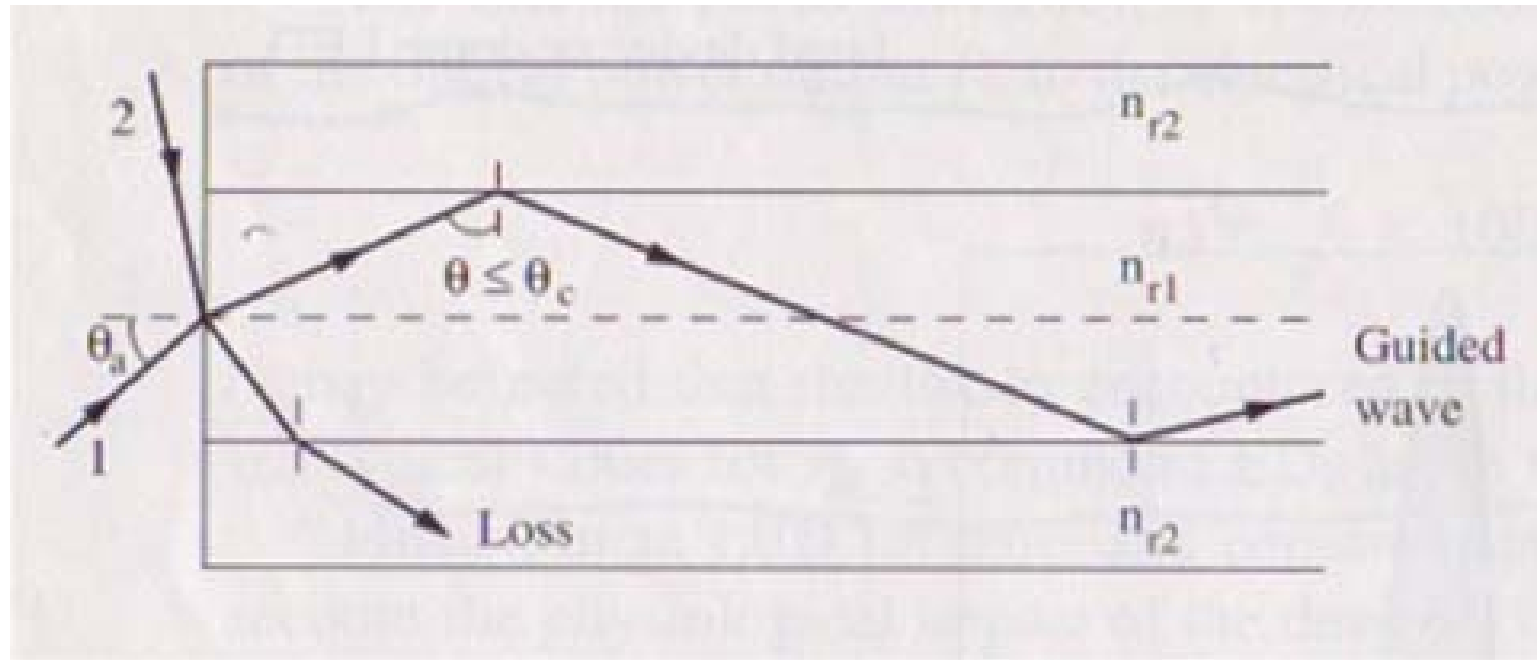
13.6 Superluminescent Diodes

# Burrus Type Surface Emitting LED



- Avoid reabsorption of the emitted light in the top of n-GaAs
- Selective etching of GaAs, but not AlGaAs (using chemical solution)
- The thin  $\text{SiO}_2$  layer in the back isolates the contact layer (heat-sink)
- Easily align Fibre
- High forward radiance and high current density due to using low contact resistance of n-GaN

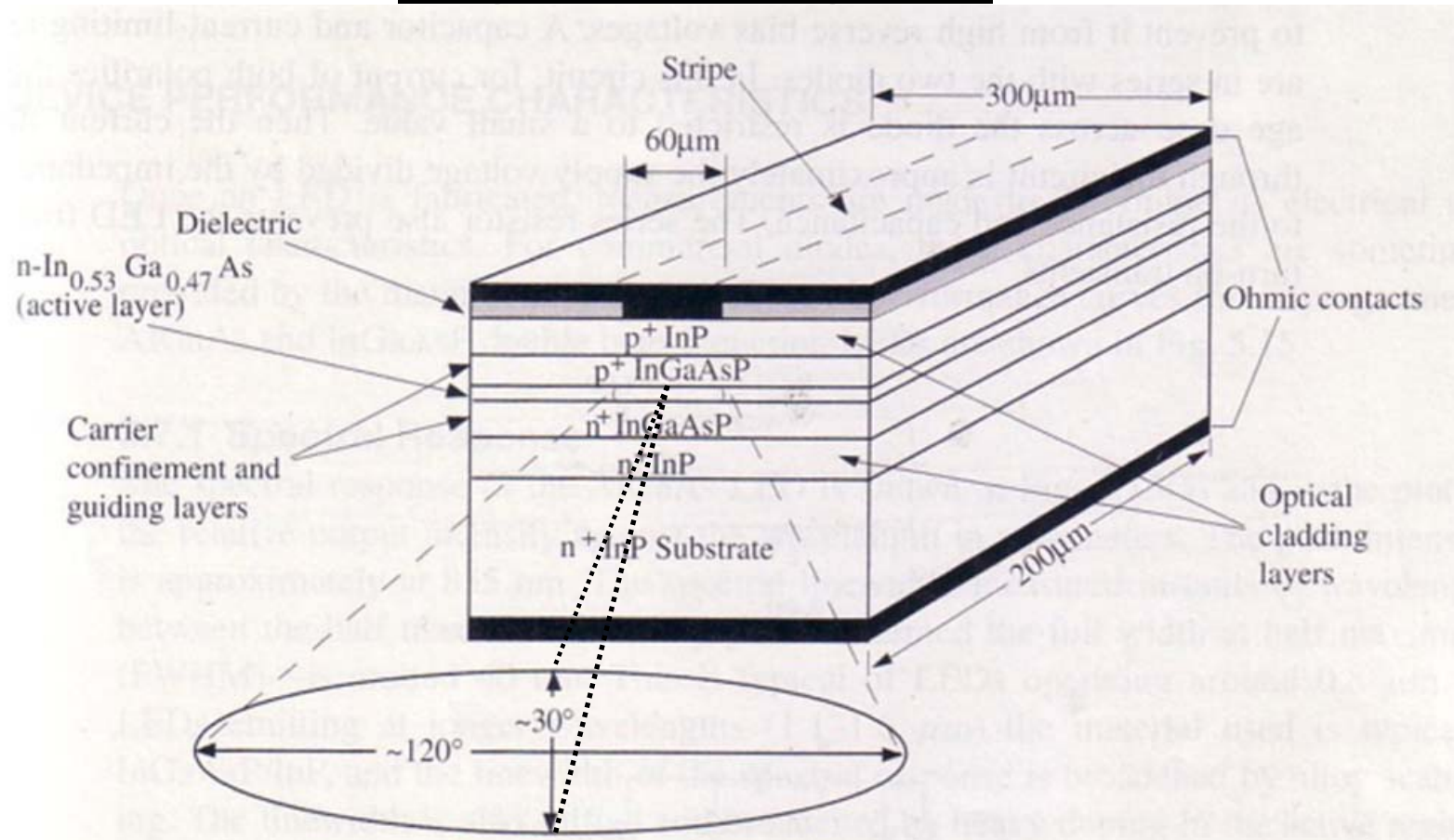
# Coupling Loss



$$\text{coupling efficiency} = \frac{\text{power coupled into the fibre}}{\text{power emitted from the source}}$$

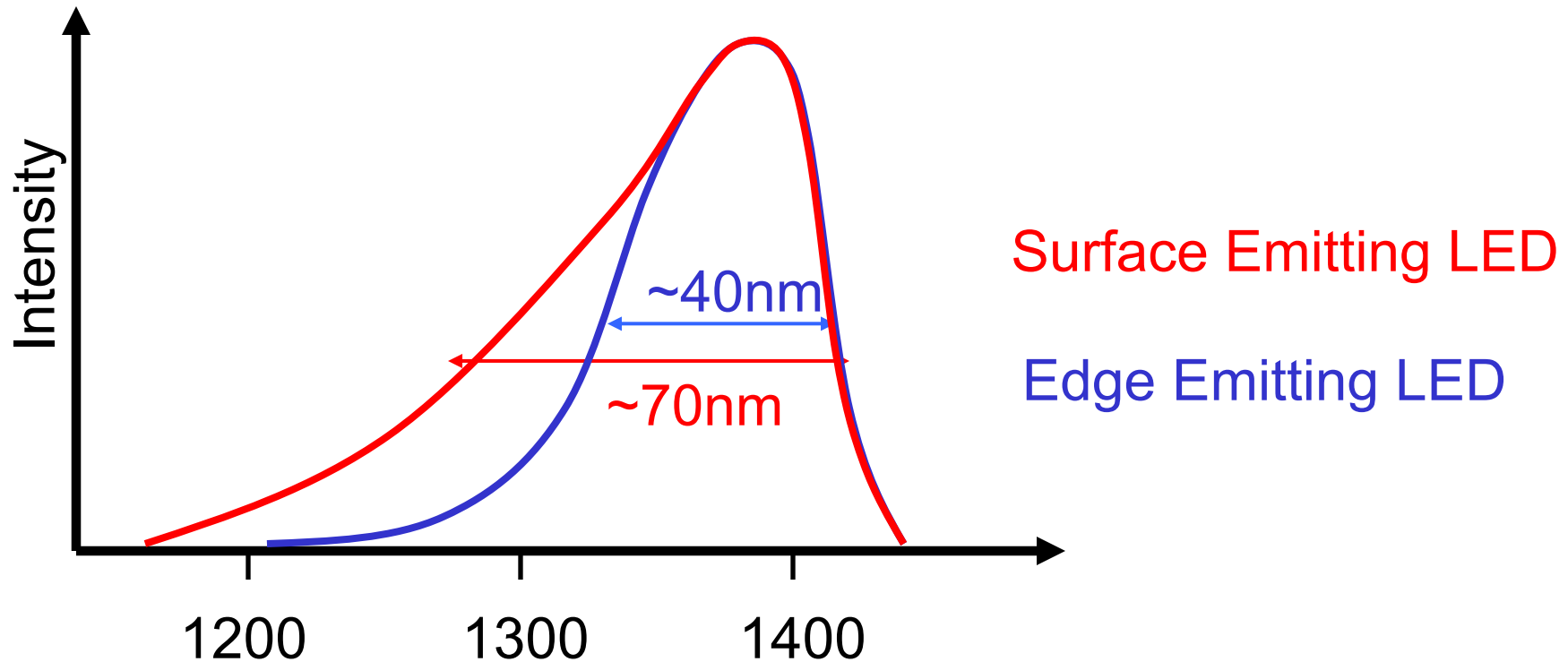
**Burrus Type Surface Emitting LED: typically 1-2%**  
**Lens coupling: improving coupling efficiency to 5-15%**

# Edge Emitting LED



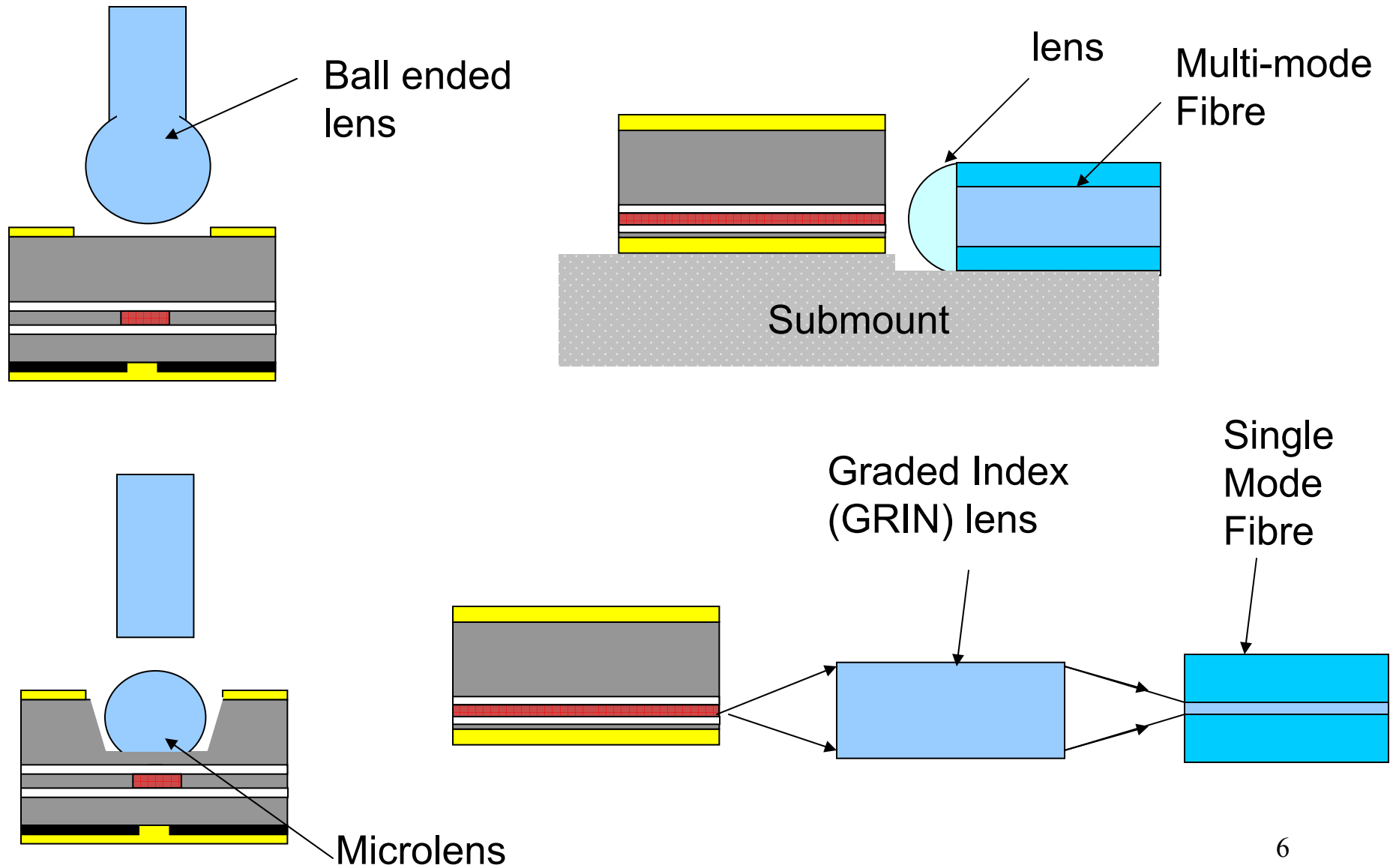
- Similar to laser structure but without a feedback cavity
- Cladding layer: photons generated in a thin active layer spread into the guiding layer and cladding layer without causing reabsorption.
- Waveguide: reduce the divergence of the emitted radiation vertically, allowing more efficient coupling of the radiated beam into fibres

# Output Spectrum

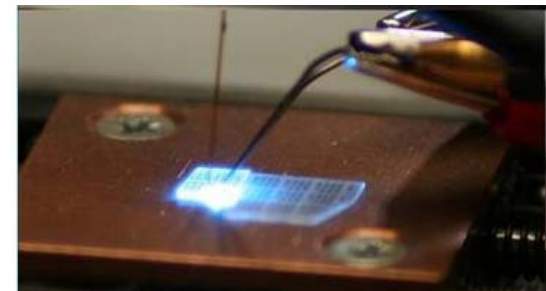
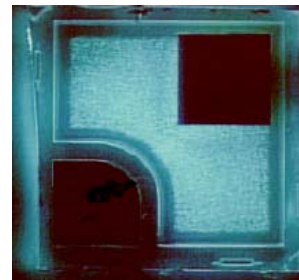
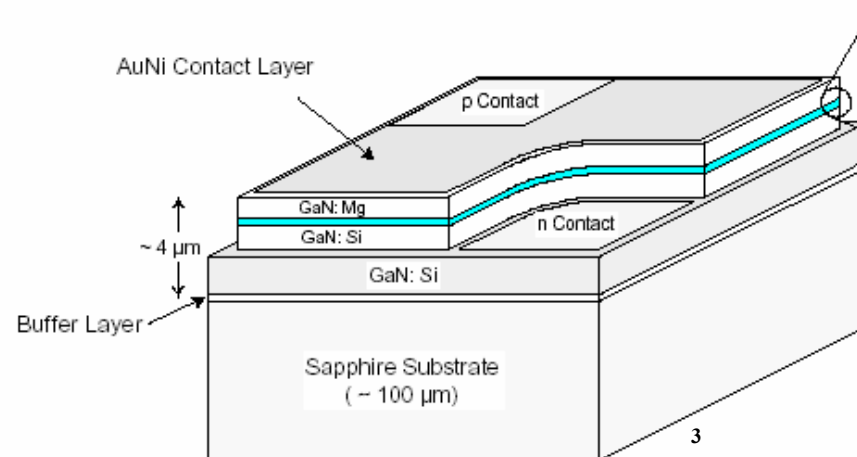
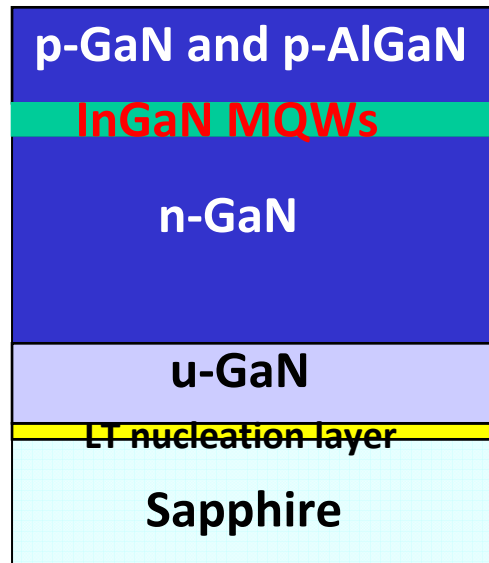


Edge emitter – high energy (low wavelength) light tends to be re-absorbed – emission is convolution of emission

# Fibre – LED Coupling



# LED Design Growth and Fabrication

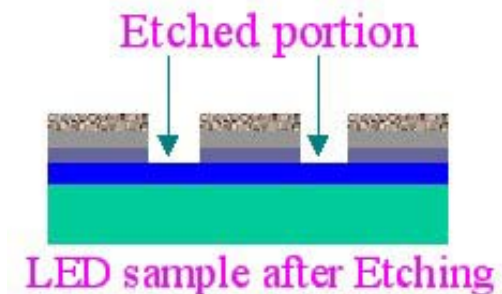
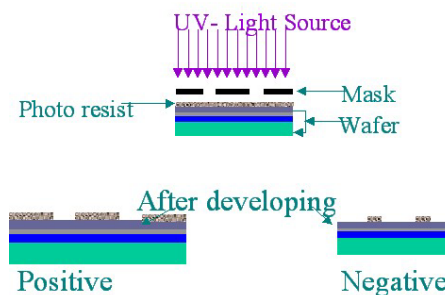
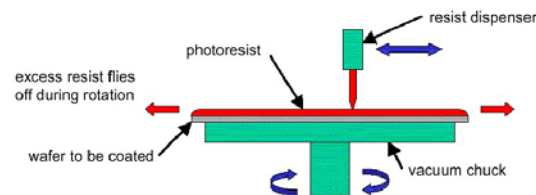


Industry:

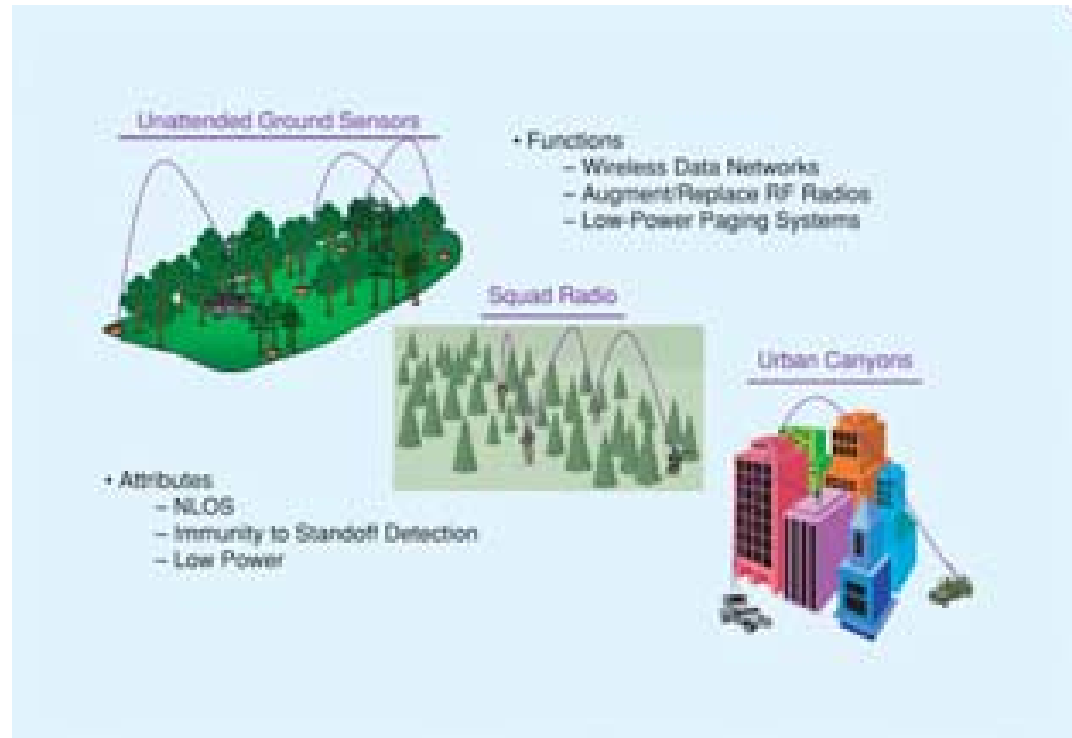
Growth: multiple-wafer MOCVD or MBE

Fabrication: lithograph and dry-etching technology ( $350 \times 350 \mu\text{m}^2$ )

Package: Epoxy dome lens



# Non-line-of-sight Communication (NLOS)

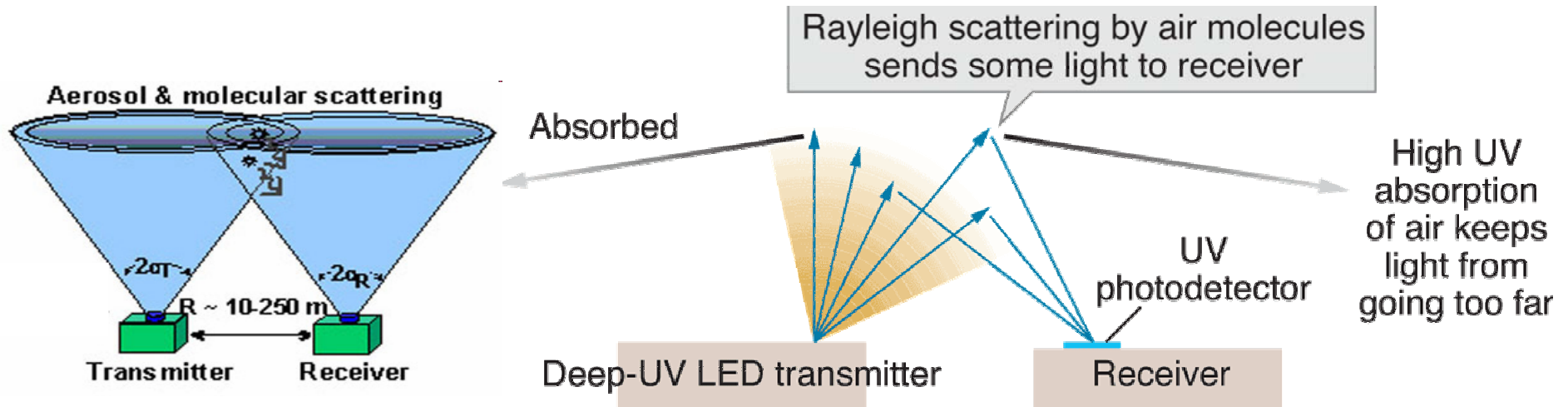


## Short distance wireless communication:

- Transmission across a path that is partially blocked
- NLOS has become more popular in the context of wireless local area networks (WLANs)
- Military applications: require a short distance communication and security

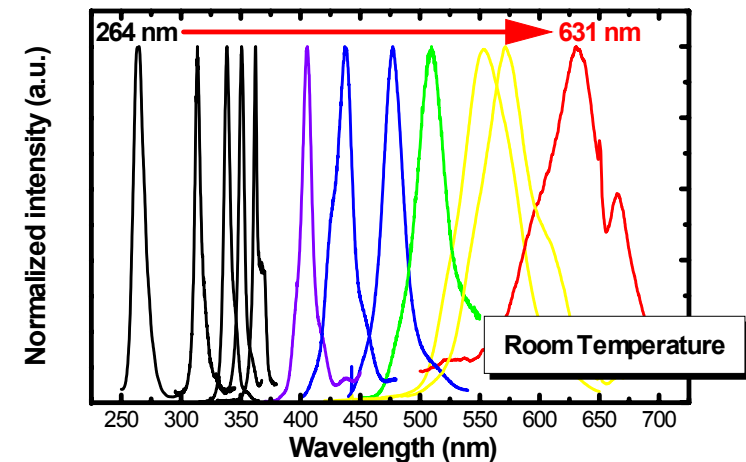
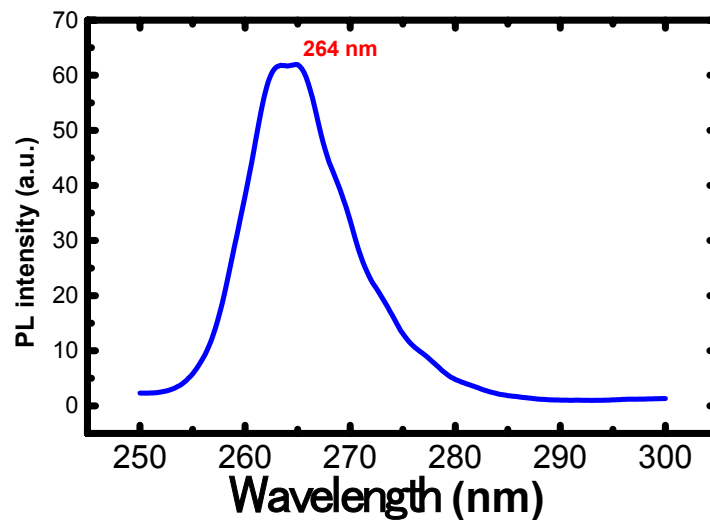
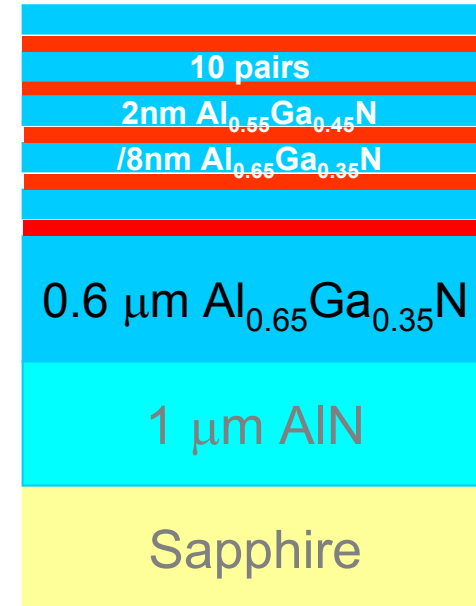
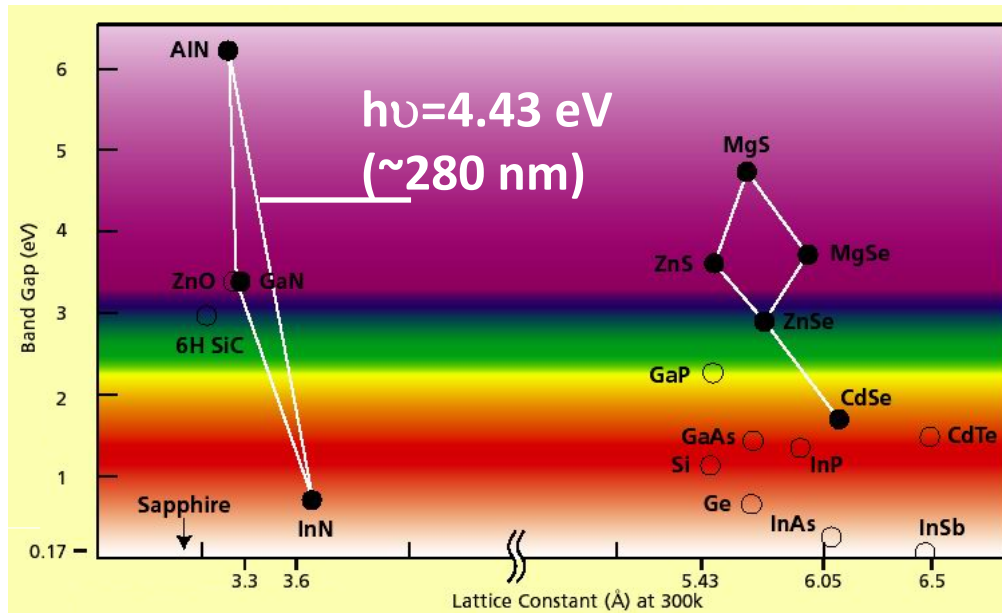


# Mechanism for NLSO



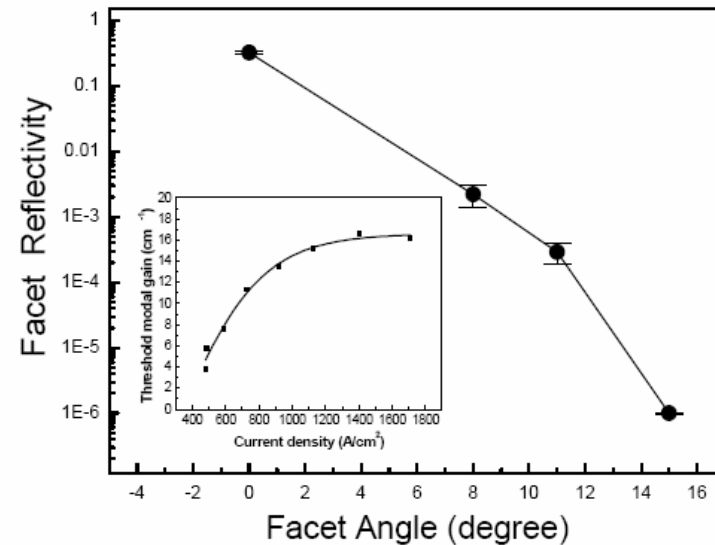
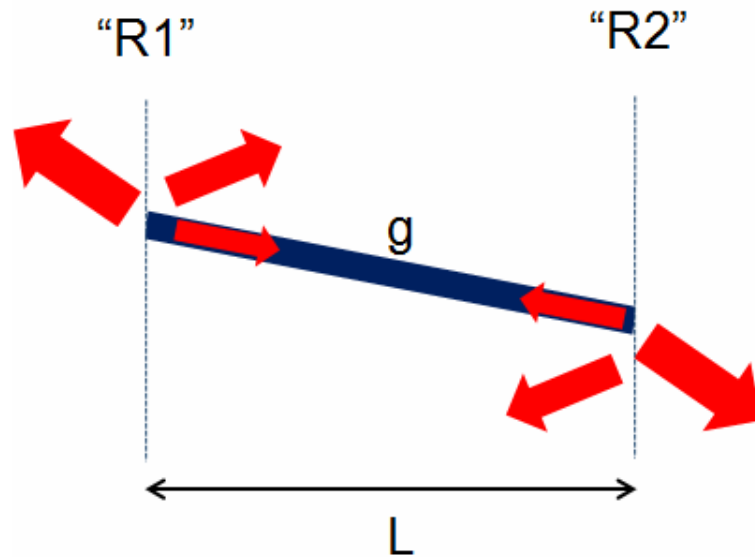
- Basically, it is due to **Rayleigh scattering**: Scattering of light by particles with a size  $\leq$  wavelength of light
- **Rayleigh scattering** requires short wavelength: Scattering  $\propto \lambda^{-4}$
- Deep UV: strong absorption
- Visible region: scattering becomes weak, and not secure
- Best wavelength:  **$\lambda=280 \text{ nm}$**

# III-nitrides devices for NLOS



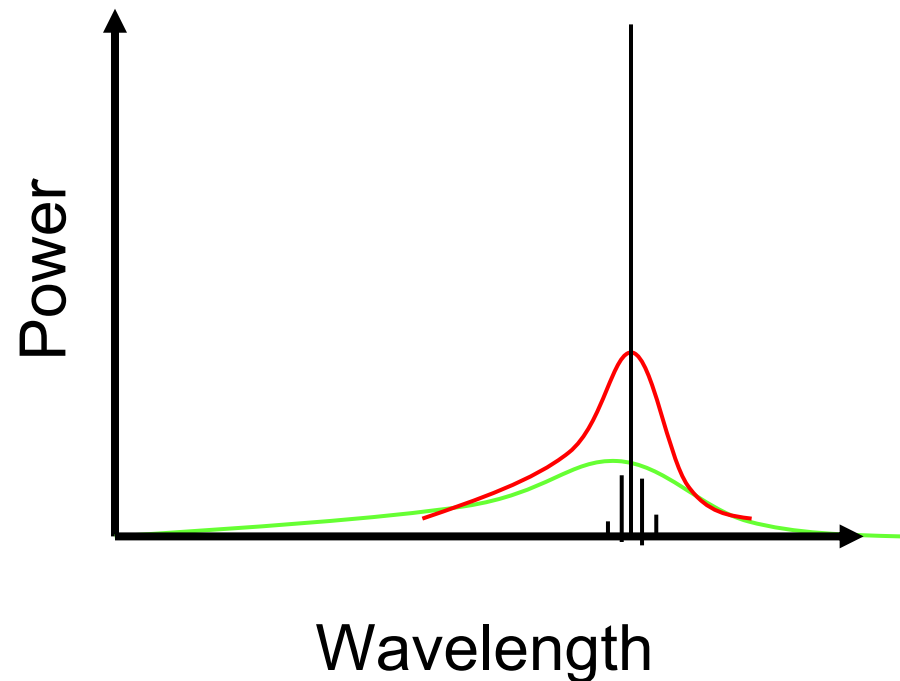
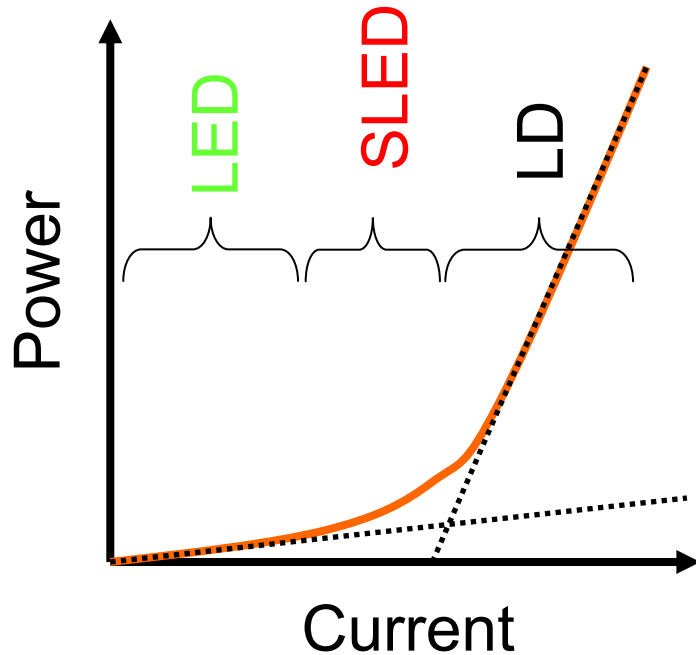
Sheffield is among only a few teams to achieve so short wavelength

# Superluminescent Diodes (i)



- Actual reflectivity can be high – as cleaved, 0.1% from facet coating
- Low effective reflectivity – back-reflected light is not guided back into waveguide
- Low effective facet reflectivity
- Used for optical amplifiers and superluminescent diodes

## Superluminescent Diodes (ii)



Combine power of laser with the wide spectral bandwidth of the LED

Uses:

- Testing DWDM systems
- Fibre sensors (fibre optic gyroscopes)
- Biomedical imaging
- High definition display which can minimise speckle issue due to laser

## **Summary - LED**

- LED-optical fibre coupling
- Burrus Type Surface Emitting LED
- Fabrication of LEDs
- Various examples of devices
- Edge emitters have narrower emission spectrum due to absorption at high energies